

分光分析による表面物理化学

近藤剛弘



筑波大学 数理物質系 物質工学域



筑波大学 数理物質融合科学センター (CiRfSE)

物質変換材料部門

共同研究者

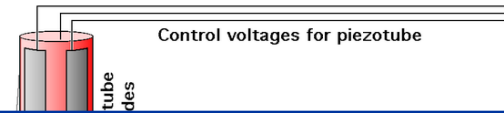


筑波大学: 中村潤児教授、Guo研究員
中村近藤研究室のメンバーと卒業生
岡田晋教授



**Web掲載用のため
イントロダクションのスライドを
一部割愛いたします**

Low temperature STM



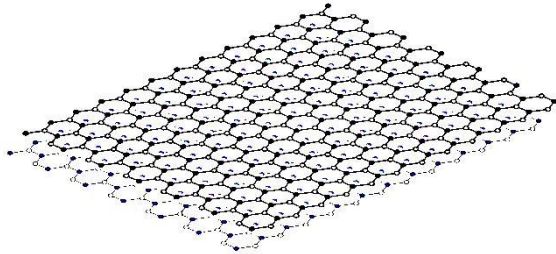
STM・STS計測では
固体表面の物理化学的な知見
特に物性や化学反応過程などを
原子分解能での顕微鏡観察と
局所分光計測で
明らかにすることが可能



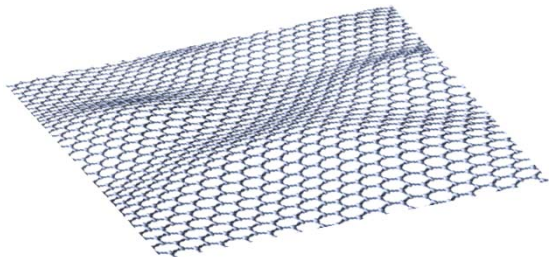
(LDOS) can be measured

Background and motivation

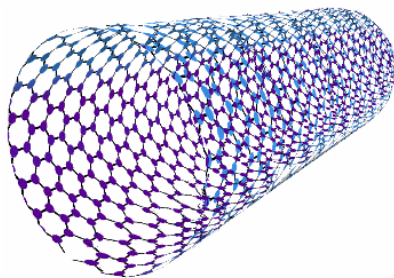
Graphitic material



Graphite (3D)



Graphene (2D)

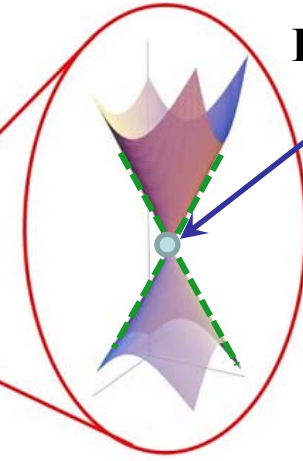
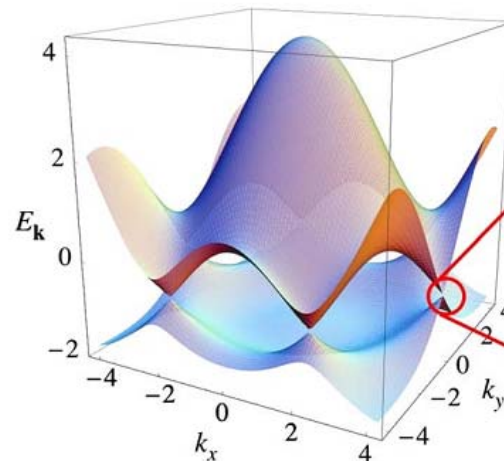


Carbon nanotube (1D)

Graphene shows specific physical and chemical properties among the graphitic materials **due to its unique electronic structure**

Zero-gap semiconductor

Linear dispersion



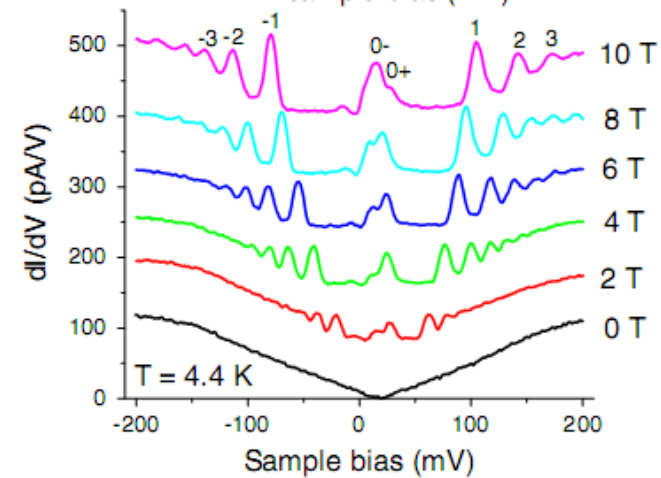
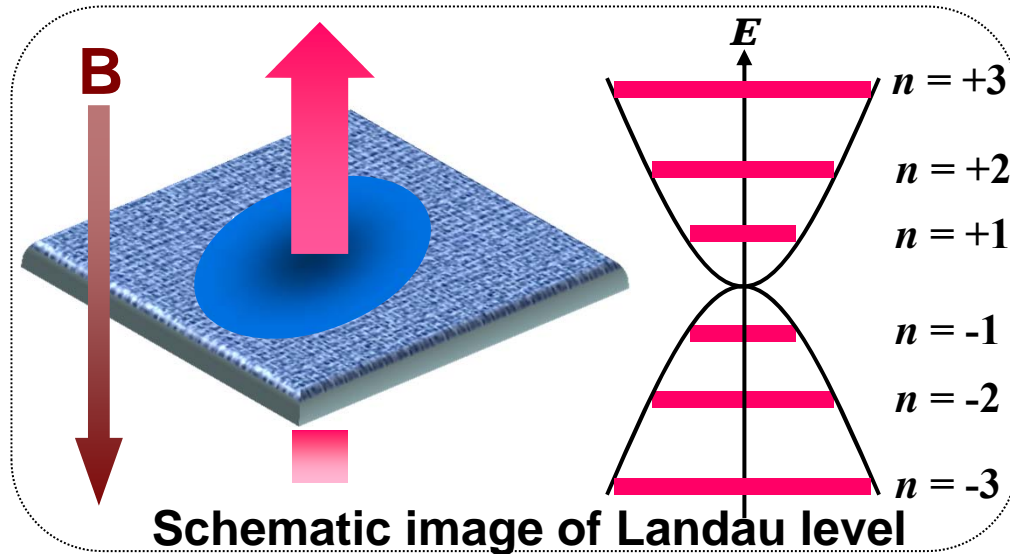
Dirac Point

Massless Dirac fermions

Graphene band structure

Graphene shows specific Landau levels under magnetic fields

Landau levels in 2D electron gas



STS of Graphene on graphite under magnetic field

La

Room-Temperature Quantum Hall Effect in Graphene



K. S. Novoselov,¹ Z. Jiang,^{2,3} Y. Zhang,² S. V. Morozov,¹ H. L. Stormer,² U. Zeitler,⁴ J. C. Maan,⁴
G. S. Boebinger,³ P. Kim,^{2*} A. K. Geim^{1*}

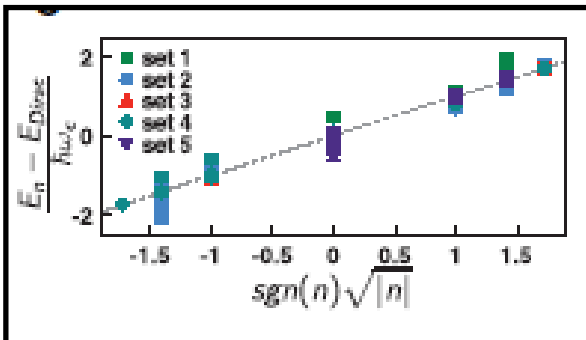
Novoselov et al., Science, 315 (2007) 1379

04

Large energy difference of graphene Landau levels is known to lead to **Quantum Hall effects at room temperature**

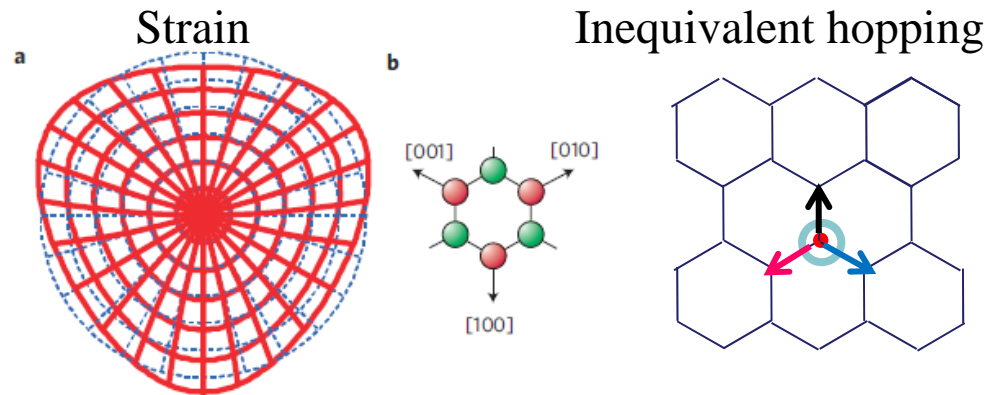
Graphene Landau level appeared at $B = 0$ T

Nano-bubble of graphene
on Pt(111)



$$E \propto \sqrt{n}$$

N. Levy et al.,
Science, **329** (2010) 544.



Non-uniform shear strain

Inequivalent hopping

$$u_{xx} = \frac{\partial u_x}{\partial x}, \quad u_{yy} = \frac{\partial u_y}{\partial y}, \quad 2u_{xy} = \frac{\partial u_x}{\partial y} + \frac{\partial u_y}{\partial x}$$

Ando, et al., Phys. Rev. B **65** (2002) 235412.
Neto et al., Rev. Mod. Phys. **81** (2009) 109.

Gauge field

$$\mathbf{A} = \frac{\beta}{a} \begin{pmatrix} u_{xx} - u_{yy} \\ -2u_{xy} \end{pmatrix} \quad B_S = \frac{\partial A_y}{\partial x} - \frac{\partial A_x}{\partial y}$$

Geim, et al., Nature Phys. **6** (2010) 30

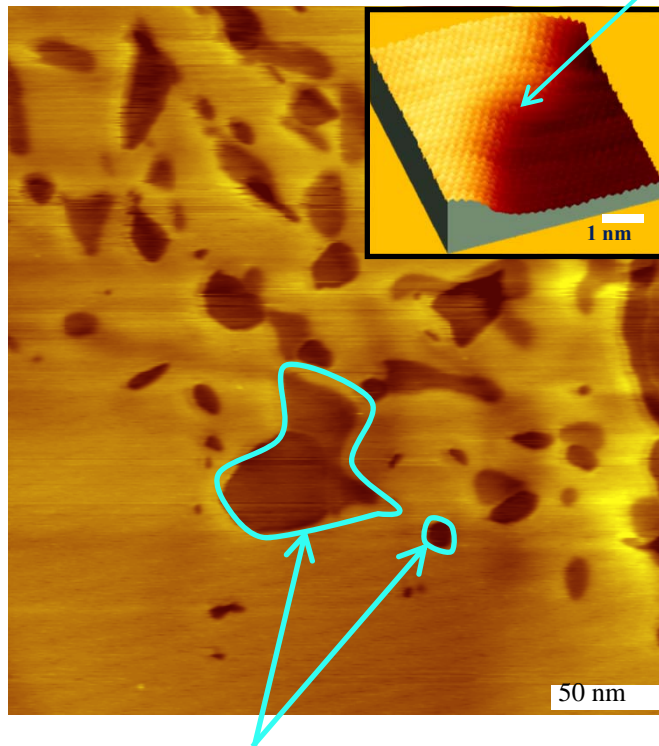
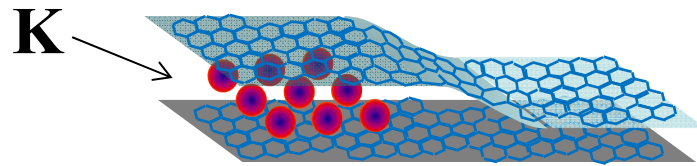
Pseudo-magnetic field

$$\vec{B}_S = \vec{\nabla} \times \vec{A}$$

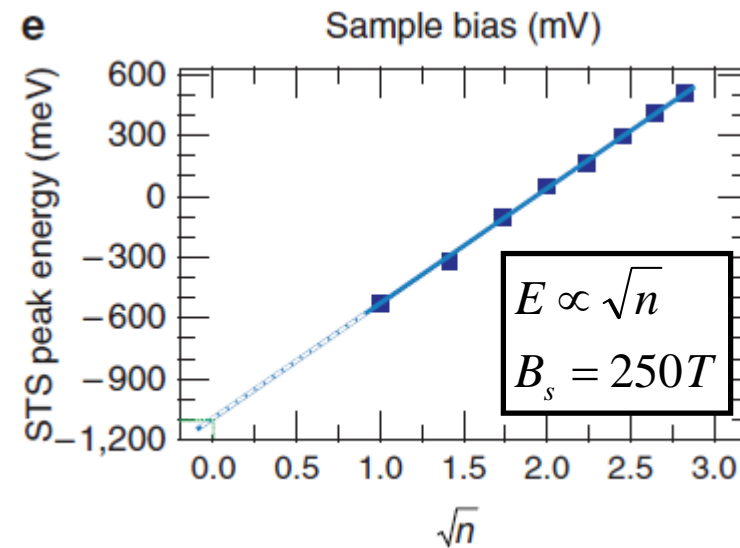
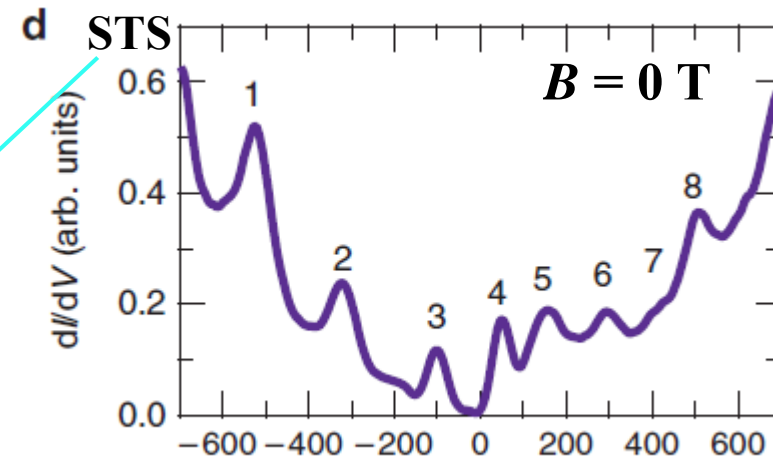
Landau levels appearance are ascribed to the
strain-induced pseudo-magnetic fields

We have also observed Landau levels at $B = 0T$

Potassium (K) partially intercalated graphite

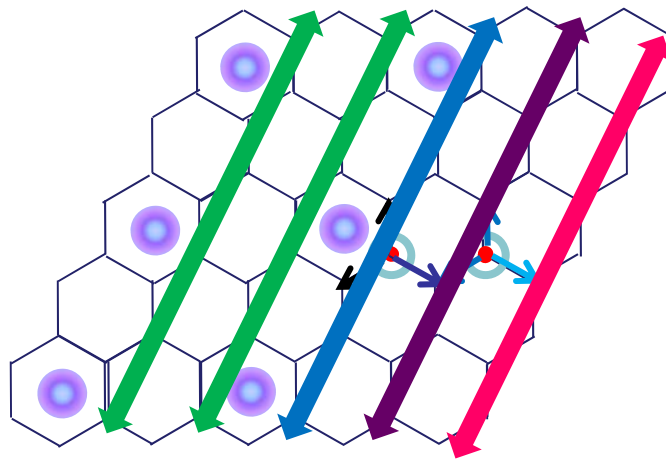
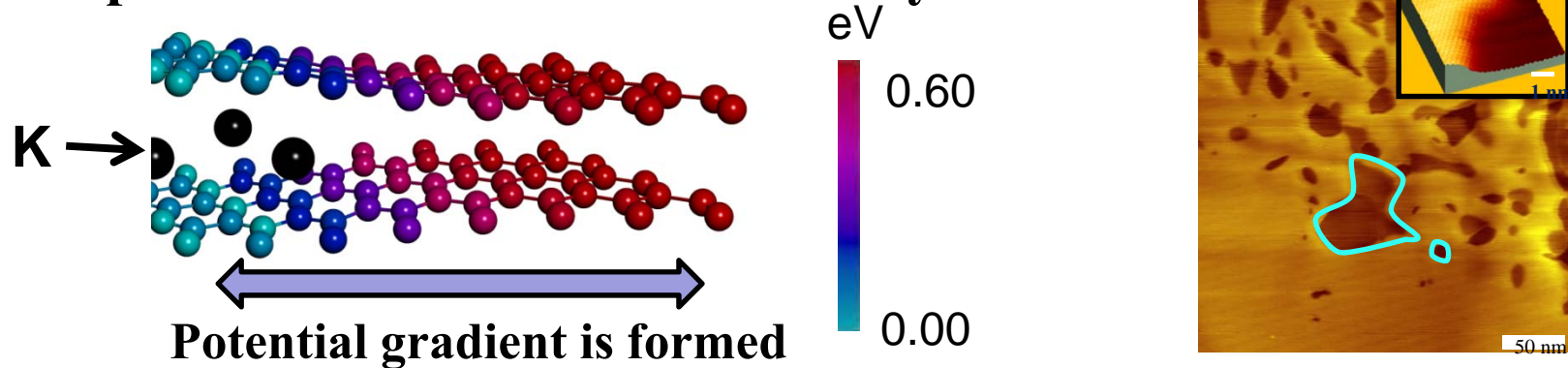


K-free domains (Nanovalleys)



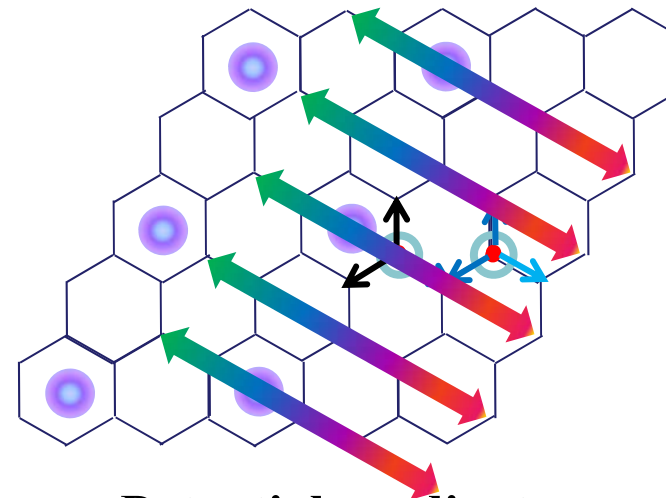
Our proposed “domain model” for pseudo magnetic fields

On-site potential of carbon calculated by DFT



Equipotential contour

Equivalent hopping in the contour direction



Potential gradient

Inequivalent hopping along the gradient direction

Gradient of on-site potentials results in inequivalent hopping

Recent progress

To prove the domain-model as another origin for the pseudo-magnetic field



We have observed Landau levels of **bilayer graphene** at the **atomically flat area** of nitrogen-doped graphite at $B = 0$ T

Experiment

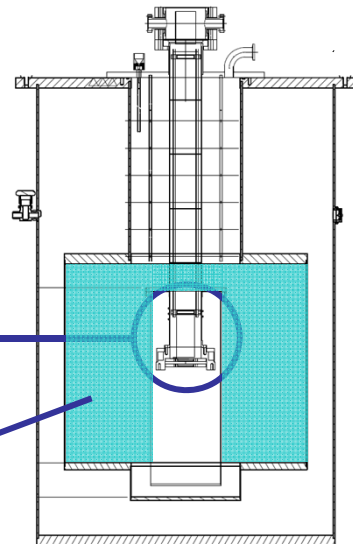
Low temperature STM



Measurement chamber

STM

Liquid He



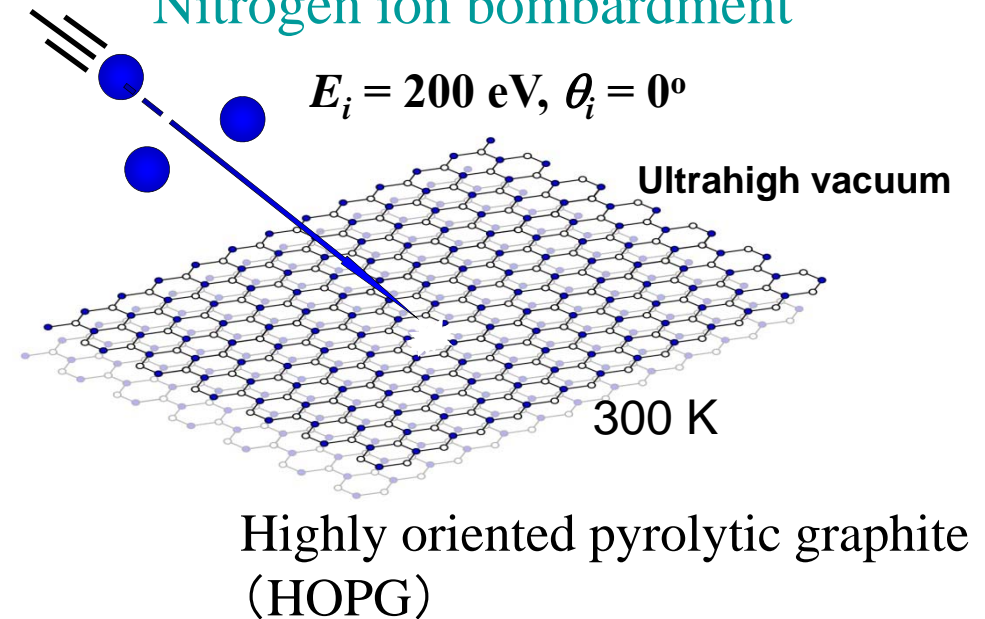
1. Cleaning of HOPG surface

- (1) Cleaving HOPG at atmosphere
- (2) 940K annealing (30 min.) in UHV

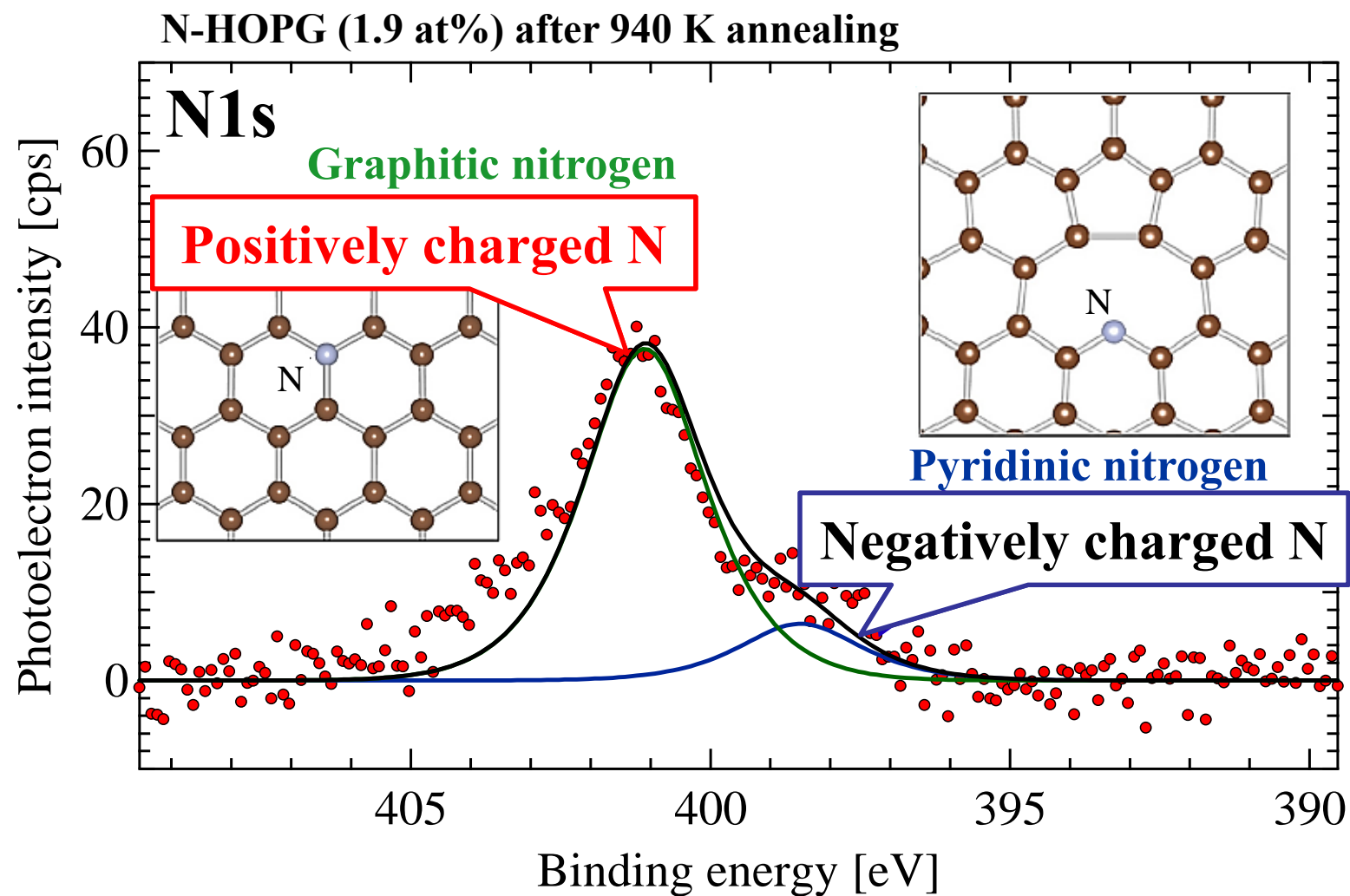
2. Nitrogen doping

- (1) Nitrogen ion bombardment
(N/C : <0.04, 0.04, 1.9 at %)
- (2) 940 K annealing (30 min.)

Nitrogen ion bombardment



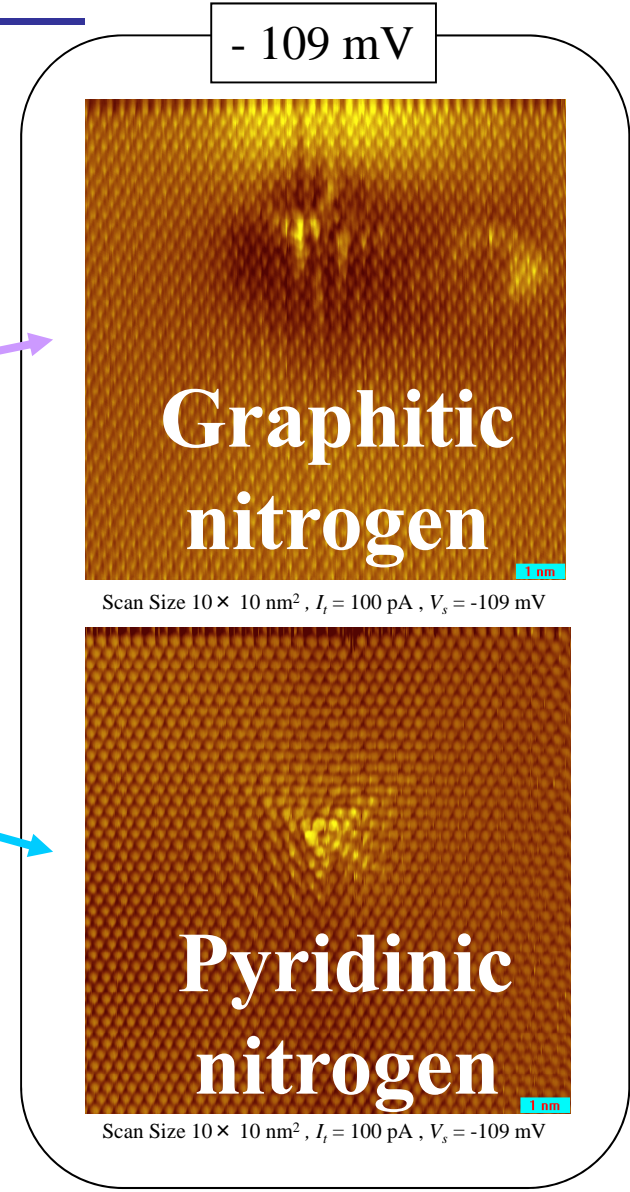
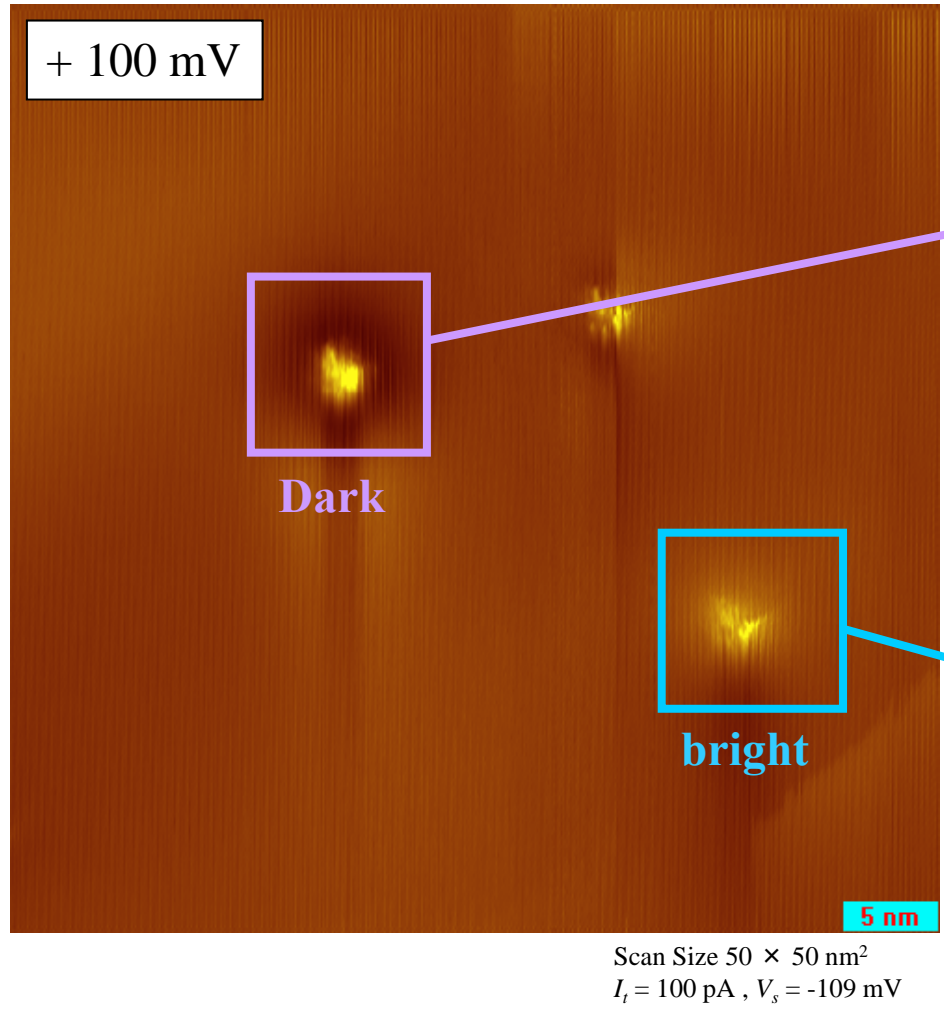
N1s XPS spectrum of nitrogen doped graphite



Graphitic nitrogen (positively charged N) is dominant

STM image of nitrogen doped graphite

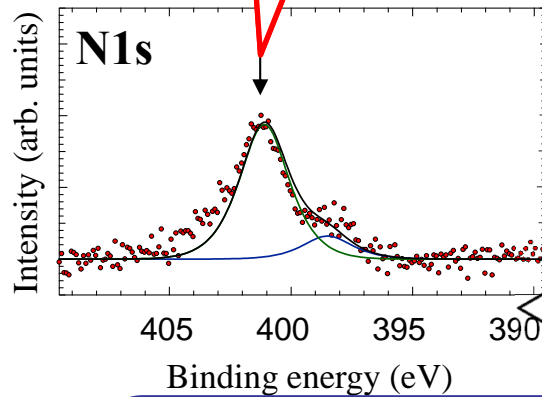
N-HOPG (<0.04 at%) after 940 K annealing



Two types of defect are observed !

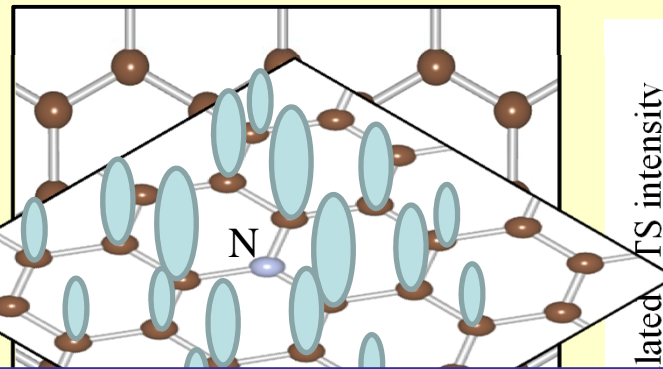
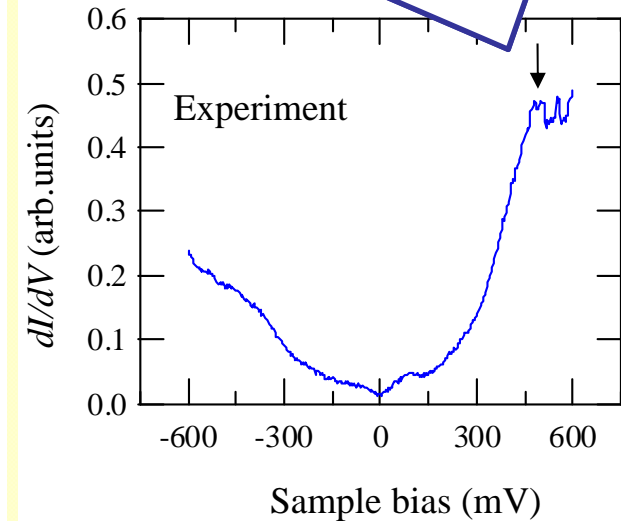
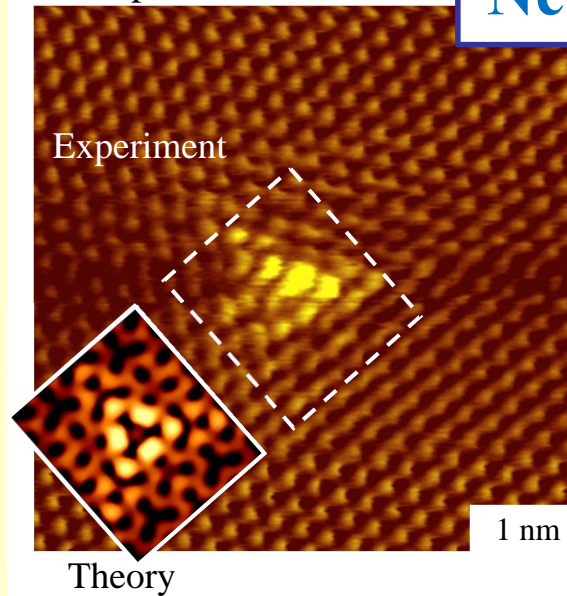
**Graphitic
nitrogen**

**Positively
charged
nitrogen**

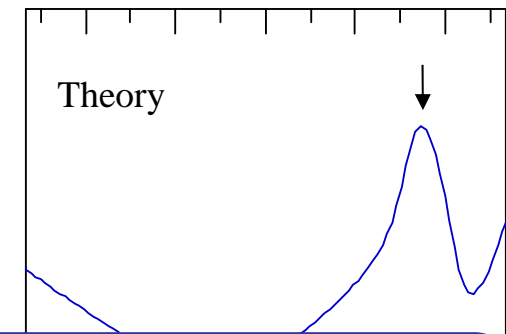


Sample bias = +0.5 V

Negatively charged carbon



lated
TS intensity

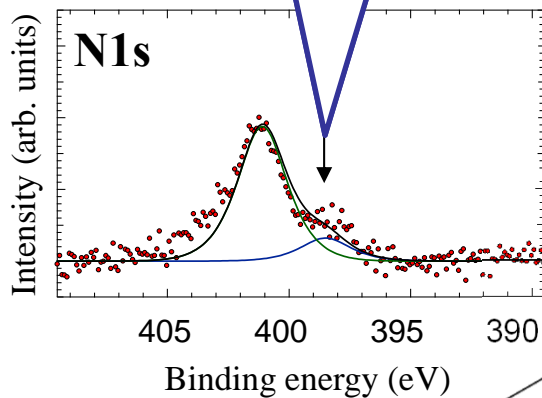


**Carbon atoms around graphitic nitrogen
may act as Lewis acid**

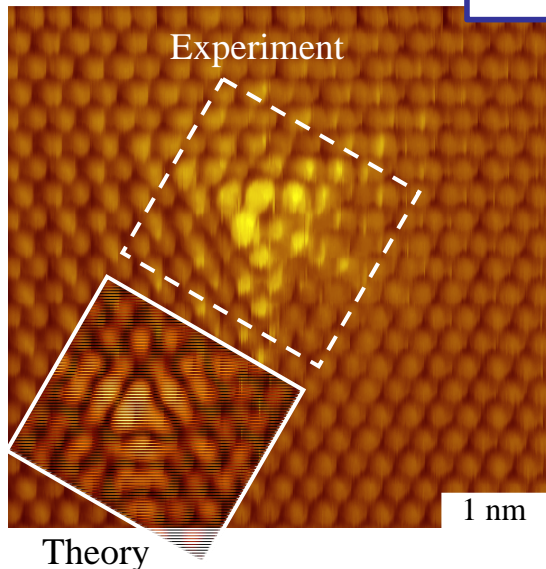
**Carbon atoms around graphitic nitrogen
may act as Lewis acid
at occupied region !**

Pyridinic nitrogen

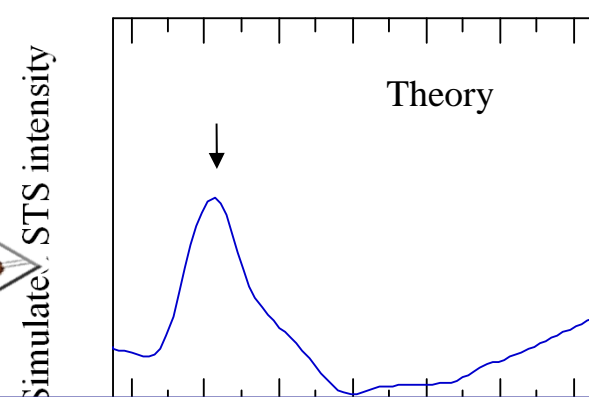
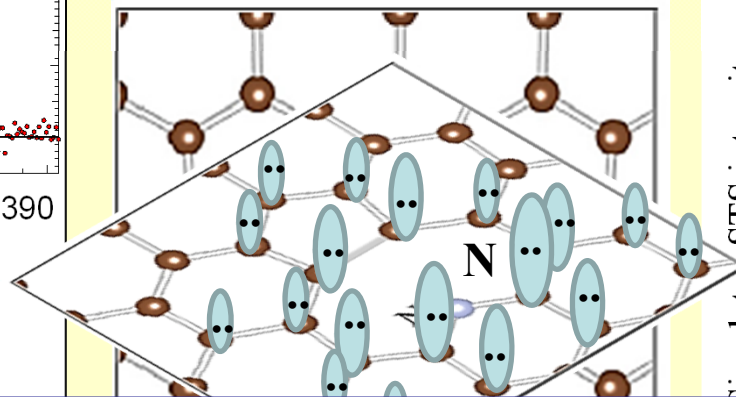
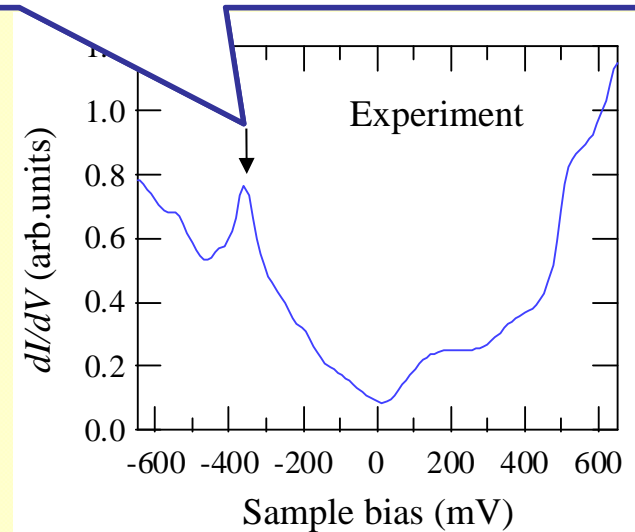
Negatively charged nitrogen



Sample bias = -0.1 V



Positively charged carbon



Carbon atoms around pyridinic nitrogen

may act as **Lewis base**
electron lone pair

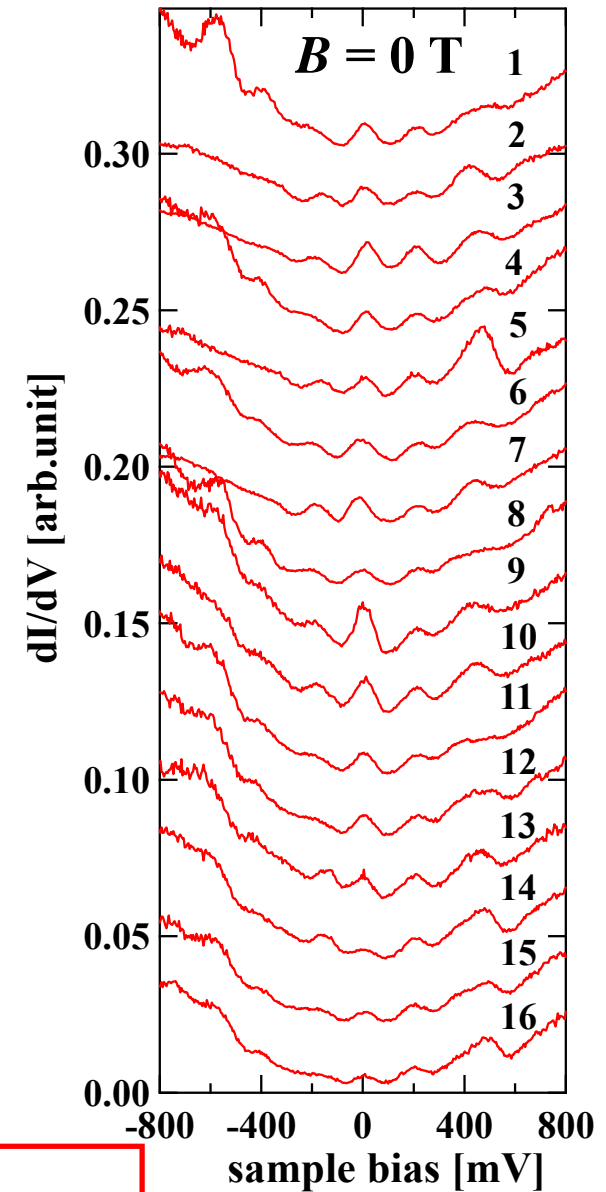
Carbon atoms at occupied region !

STS spectra on nitrogen doped graphite

N-HOPG (0.04 at%) after 940 K annealing

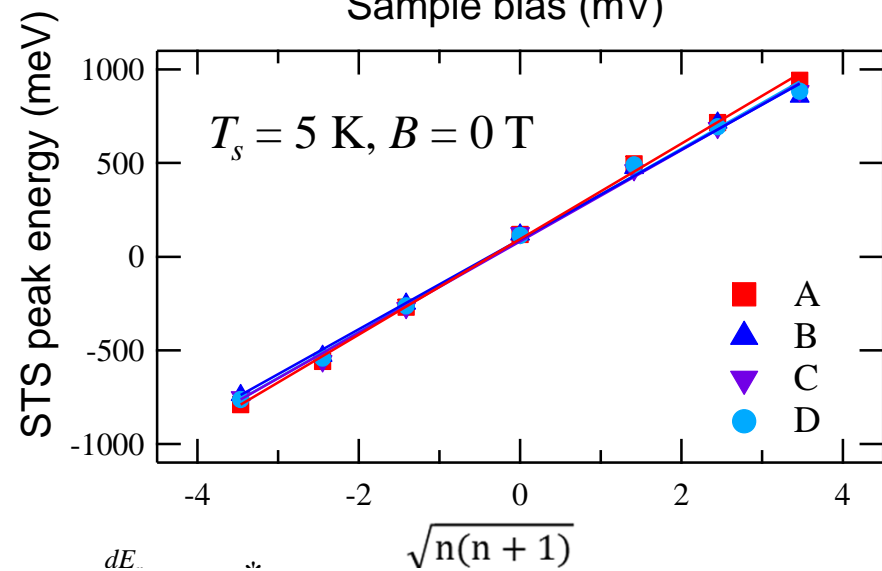
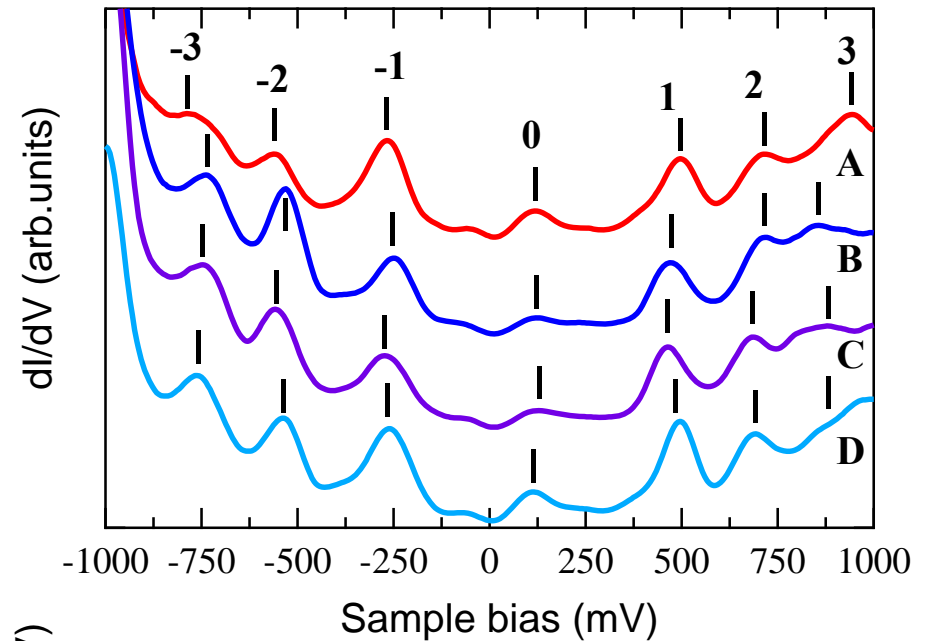
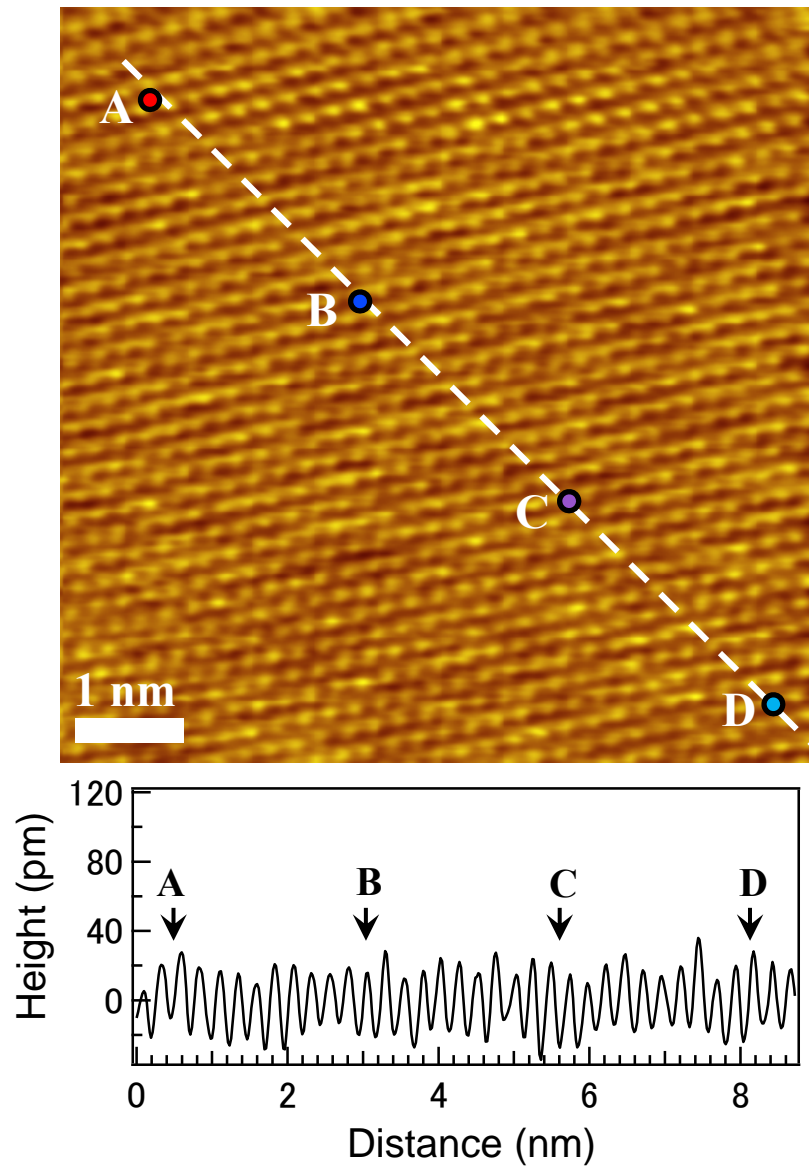


$50 \times 50 \text{ nm}^2$, 800 mV, 100 pA $T_s = 5 \text{ K}$, $B = 0 \text{ T}$



Many peaks appear in STS spectrum

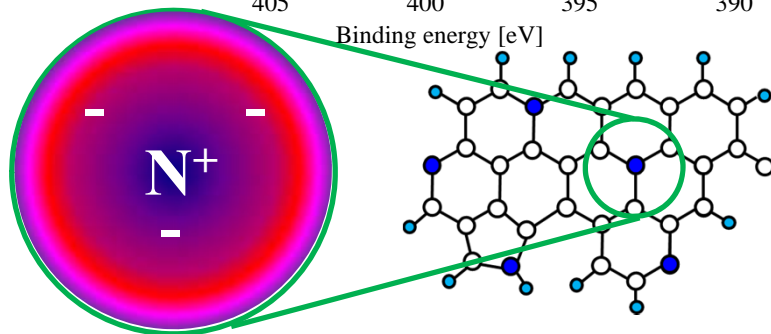
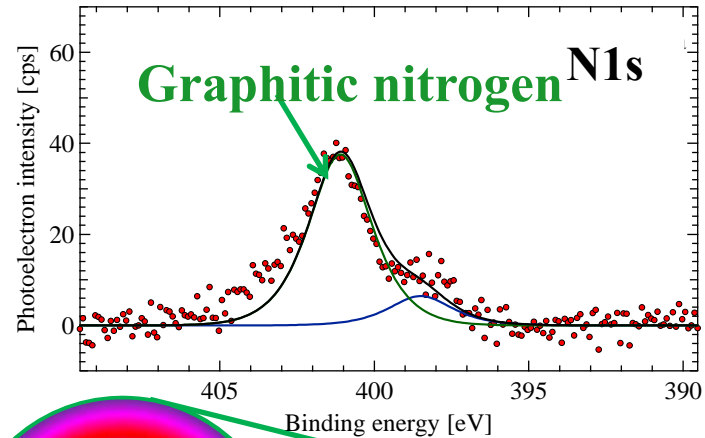
STM and STS on nitrogen doped graphite at $B = 0\text{T}$



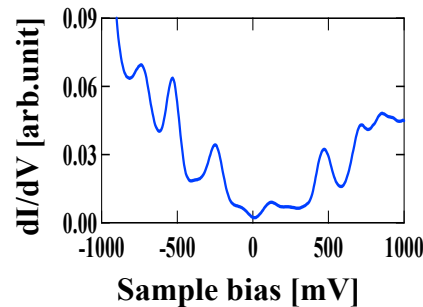
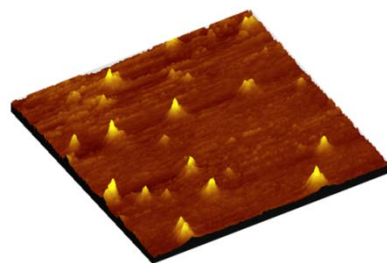
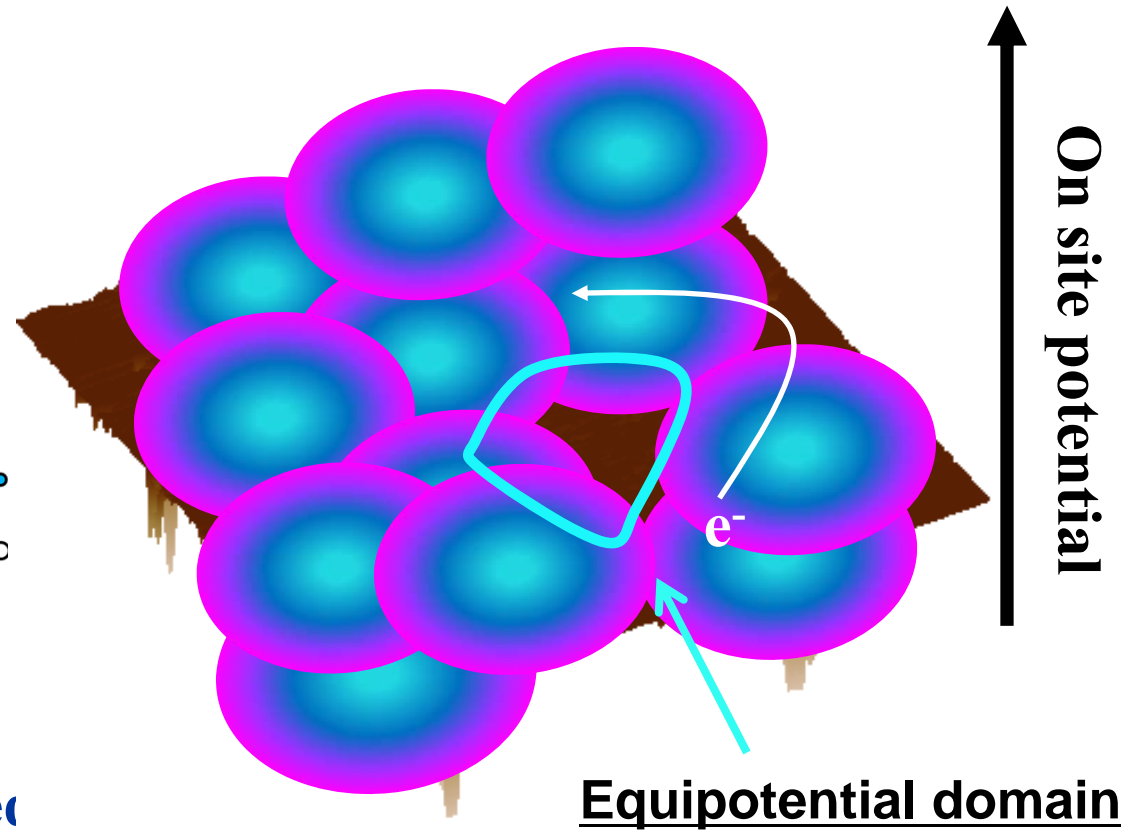
Landau levels of **bilayer graphene** appear at **FLAT** area !

Why LL-like peaks appear in STS at $B = 0$ T

Nitrogen doped-graphite



Schematic image of potential

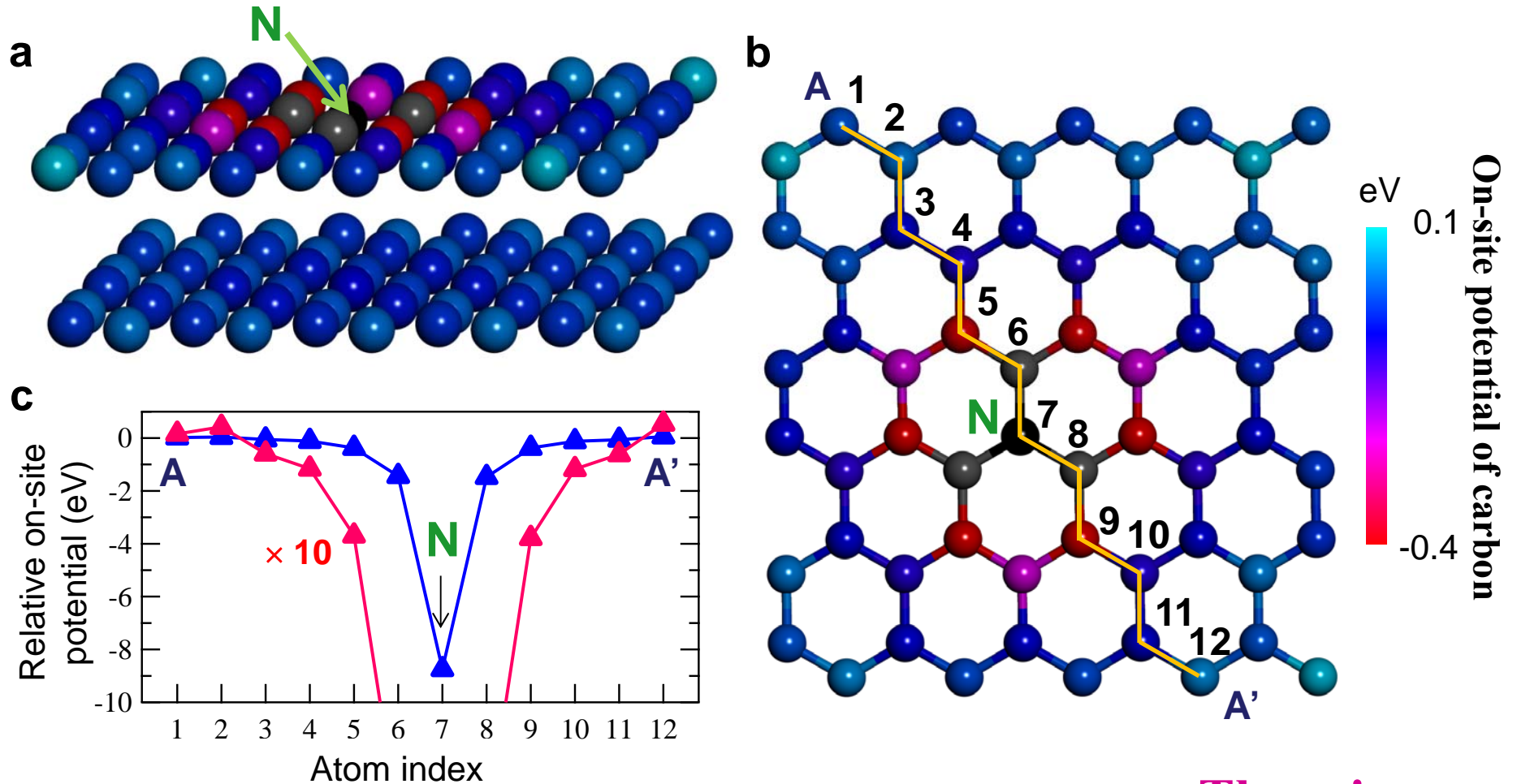


Inequivalent hopping along
the potential gradient

LLs formation at $B = 0$ T

Gradient of on-site potentials around graphitic nitrogen

DFT calculation of nitrogen dope bilayer graphene



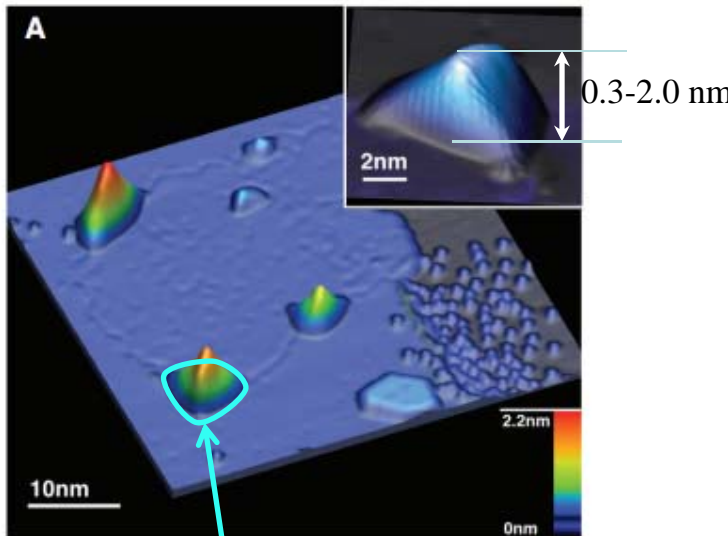
On-site potential of carbon next to nitrogen is 1.5 eV lower than carbon far from nitrogen!

There is a gradient of on-site potentials

Summary

- Landau level peaks of bilayer graphene are observed in STS at the atomically flat area of nitrogen doped HOPG at $B = 0$ T.
- Domain model can explain the LL appearance. (difference in the on-site potential)

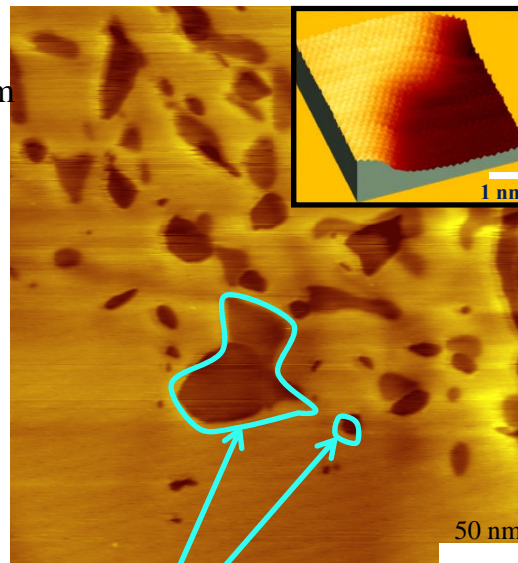
Strain



Science, 329, 544 (2010)

Nanobubble on Pt

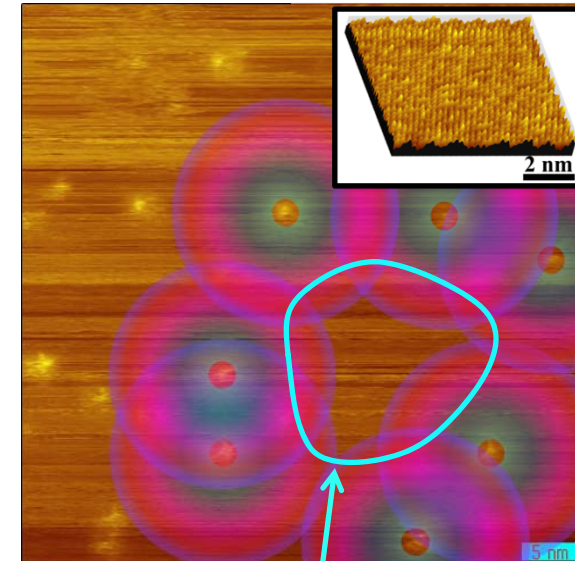
K-intercalated



Our work
Nature comm., 3, 1068 (2012)

K-free domains (Nanovalleys)

Nitrogen



Our work
Scientific Reports 5, 16412 (2015)

N doped-graphite